

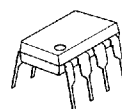
NJM4250

The NJM4250 is extremely versatile programmable monolithic operational amplifiers. A single external master bias current setting resistor programs the input bias current, input offset current, quiescent power consumption, slew rate, input noise, and the gain-bandwidth product. The device is a truly general purpose operational amplifier.

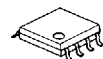
■ Package Outline

■ Absolute Maximum Ratings ($T_a=25^\circ\text{C}$)

Supply Voltage	V^+/V^-	$\pm 18\text{V}$
Differential Input Voltage	V_{ID}	$\pm 30\text{V}$
Input Voltage(note)	V_{IC}	$\pm 15\text{V}$
Power Dissipation	P_D (D-Type)	500mW
	(M-Type)	300mW
	(V-Type)	250mW
Set Current	I_{SET}	150 μA
Operating Temperature Range	T_{opr}	$-20\sim+75^\circ\text{C}$
Storage Temperature Range	T_{stg}	$-40\sim+125^\circ\text{C}$



NJM4250D



NJM4250M



NJM4250V

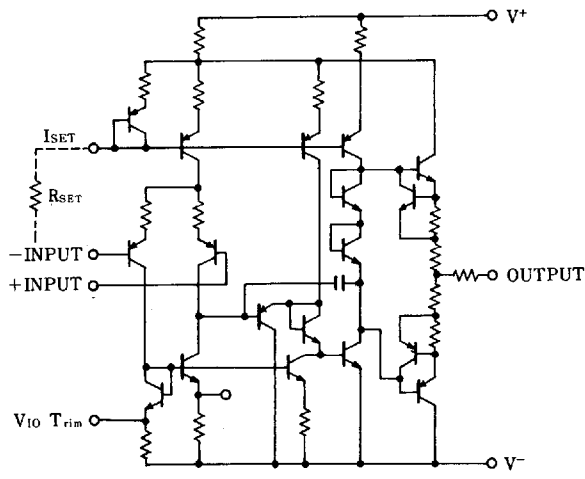
(note) For supply voltage less than $\pm 15\text{V}$, the absolute maximum input voltage is equal to the supply voltage.

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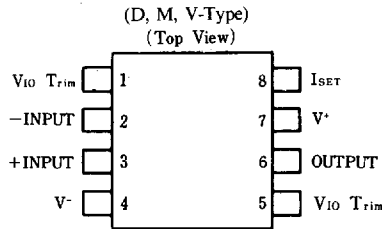
■ Electrical Characteristics ($T_a=25^\circ\text{C}$, $V^+/V^- = \pm 15\text{V}$)

Parameter	Symbol	Test Condition	$I_{SET}=1\mu\text{A}$		$I_{SET}=10\mu\text{A}$		Unit
			Min.	Max.	Min.	Max.	
Input Offset Voltage 1	V_{IO1}	$R_S \leq 100\text{k}\Omega$	—	.5	—	6	mV
Input Offset Voltage 2	V_{IO2}	$V^+/V^- = \pm 1.5\text{V}$, $R_S \leq 100\text{k}\Omega$	—	5	—	6	mV
Input Offset Current	I_{IO}		—	6	—	20	nA
Input Bias Current 1	I_{B1}		—	10	—	75	nA
Input Bias Current 2	I_{B2}	$V^+/V^- = \pm 1.5\text{V}$	—	10	—	75	nA
Large Signal Voltage Gain 1	A_{V1}	$V_o = \pm 10\text{V}$, $R_L \geq 100\text{k}\Omega$	96	—	—	—	dB
Large Signal Voltage Gain 2	A_{V2}	$V_o = \pm 10\text{V}$, $R_L \geq 10\text{k}\Omega$	—	—	96	—	dB
Supply Current 1	I_{CC1}		—	11	—	100	μA
Supply Current 2	I_{CC2}	$V^+/V^- = \pm 1.5\text{V}$	—	8	—	90	μA
Input Common Mode Voltage Range 1	V_{ICM1}		± 13.5	—	± 13.5	—	V
Input Common Mode Voltage Range 2	V_{ICM2}	$V^+/V^- = \pm 1.5\text{V}$	± 0.6	—	± 0.6	—	V
Maximum Output Voltage Swing 1	V_{OM1}	$R_L \geq 100\text{k}\Omega$	± 12	—	—	—	V
Maximum Output Voltage Swing 2	V_{OM2}	$V^+/V^- = \pm 1.5\text{V}$, $R_L \geq 100\text{k}\Omega$	± 0.6	—	—	—	V
Maximum Output Voltage Swing 3	V_{OM3}	$R_L \geq 10\text{k}\Omega$	—	—	± 12	—	V
Maximum Output Voltage Swing 4	V_{OM4}	$V^+/V^- = \pm 1.5\text{V}$, $R_L \geq 10\text{k}\Omega$	—	—	± 0.6	—	V
Common Mode Rejection Ratio	CMR	$R_S \leq 10\text{k}\Omega$	70	—	70	—	dB
Supply Voltage Rejection Ratio	SVR	$R_S \leq 10\text{k}\Omega$	74	—	74	—	dB

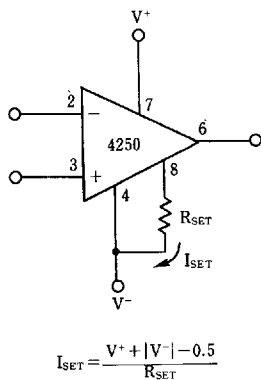
■ Equivalent Circuit



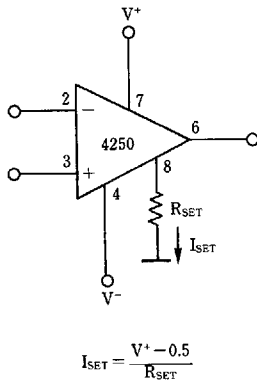
■ Connection Diagram



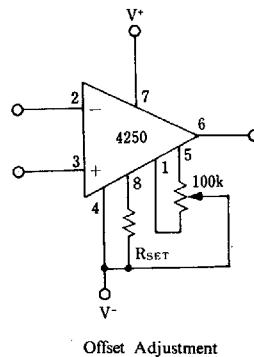
■ Typical Applications (I_{SET}, V_{IO} Adjustment)



$$I_{SET} = \frac{V^+ + |V^-| - 0.5}{R_{SET}}$$



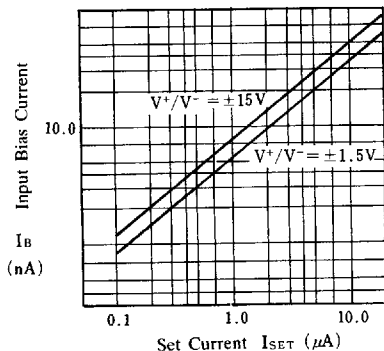
$$I_{SET} = \frac{V^+ - 0.5}{R_{SET}}$$



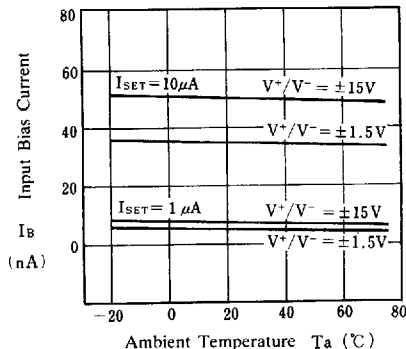
Offset Adjustment

■ Typical Characteristics

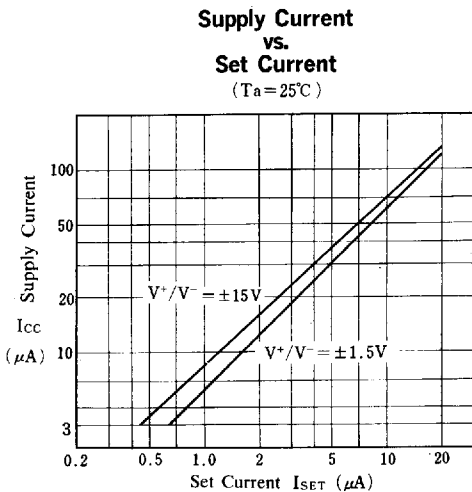
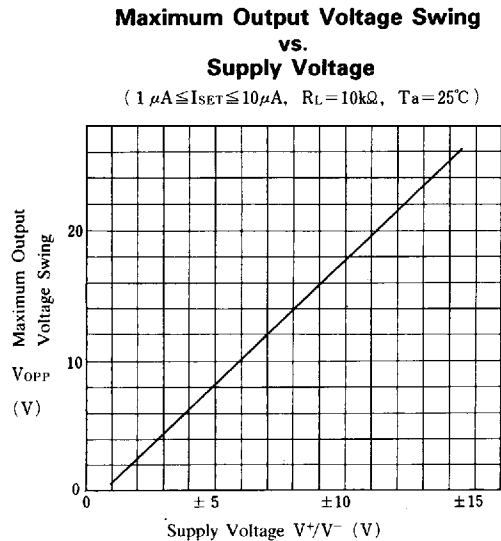
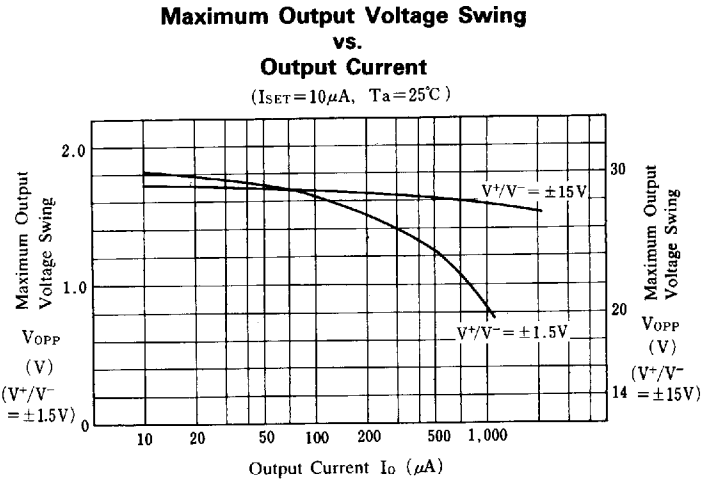
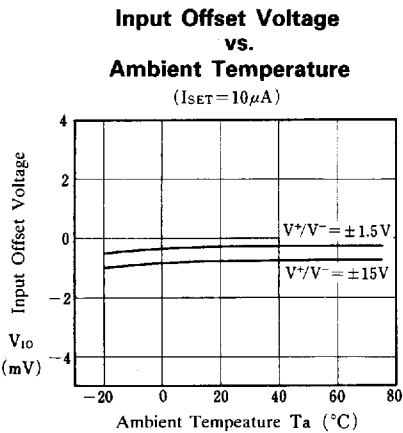
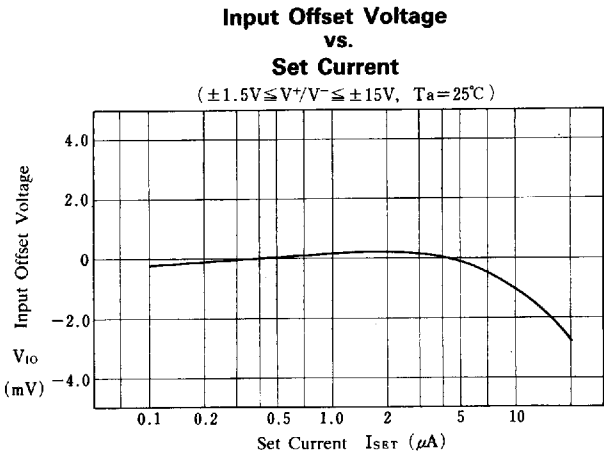
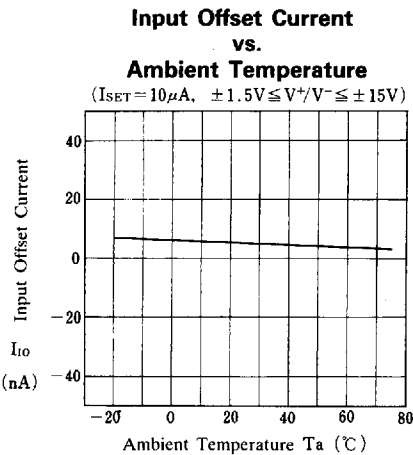
Input Bias Current vs. Set Current
(T_a = 25°C)



Input Bias Current vs. Temperature

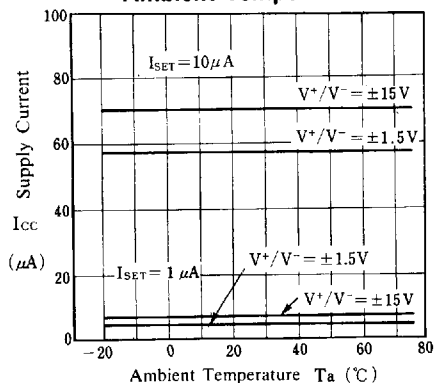


■ Typical Characteristics

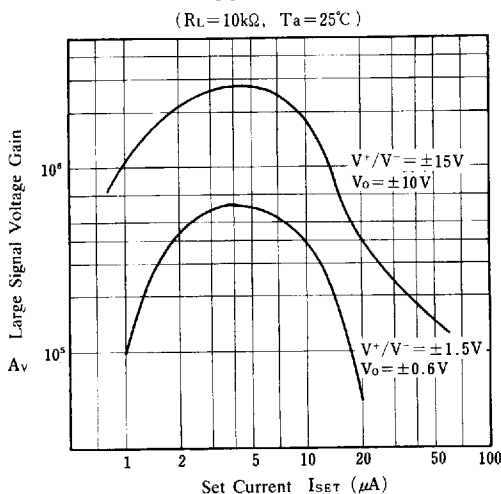


■ Typical Characteristics

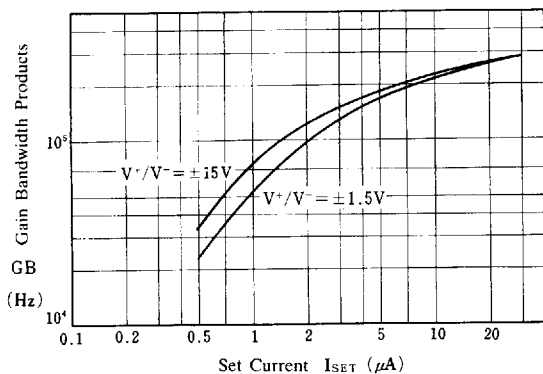
Supply Current
vs.
Ambient Temperature



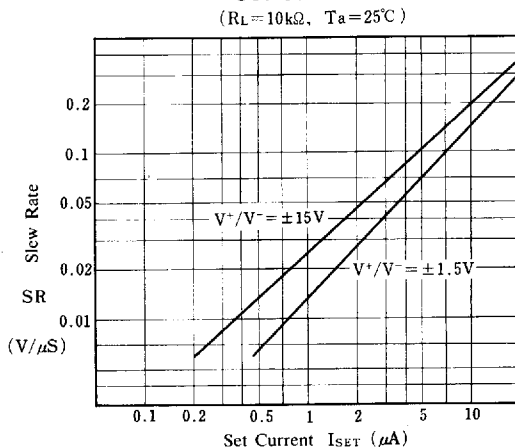
Open Loop Voltage Gain
vs.
Set Current



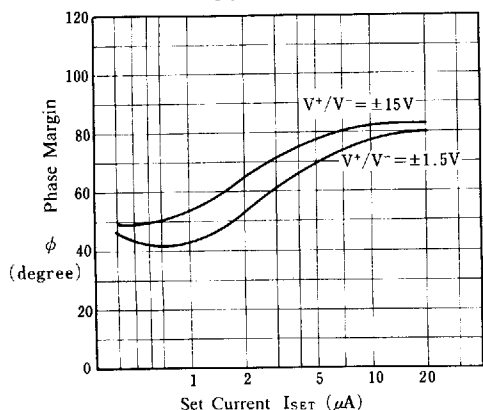
Gain Bandwidth Product
vs.
Set Current
($T_a = 25^\circ C$)



Slew Rate
vs.
Set Current



Phase Margin
vs.
Set Current



■ Typical Applications

500nW 10times Inverting Amplifier

